## Spectroscopy Amplifier

# **TechnoAP**

## A101

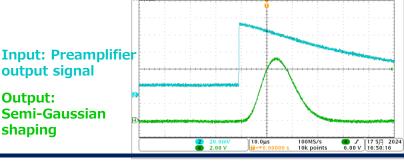
A101 is a Spectroscopy amplifier with a NIM1 width. It adopts an active filter method for waveform shaping, bringing it closer to the ideal Gaussian shaping. The amplifier uses a discrete amplification circuit with the latest low-noise FETs, achieving an input noise characteristic of less than 5 µV. Additionally, it features an active-gated baseline restoration, making it suitable for measurements at high count rates. A101 is particularly capable of achieving excellent resolution and linearity when used in measurements with HPGe semiconductor detectors.

#### **Features**

×1~1500
Semi-Gaussian Shaping Peaking Time 2.2т, Pulse width 6т
Input equivalent noise less than 5 $\mu$ V Gain $\geq$ 100 at 2 $\mu$ s.
< ±0.05% 2µsST
Active Gated Auto-threshold Method
Peak width spread up to 15%, at 2 $\mu$ s, with an input count rate of 50 kcps.

#### **Specifications**

Input Polarity	POS / NEG
Attenuator	×0.1/×1.0 Switching via internal board jumper
COARSE GAIN	×20/×50/×100/×200/×500/×1K
FINE GAIN	×0.5~×1.5
PZ ADJ	Pole-zero Adjustment, 40 $\mu$ s $\sim\infty$
DC	±40mV
Shaping Time	0.5/ 1/ 2/ 3/ 6/ 10 µs
Input Characteristics	Range: ±1.5 V, Input impedance: 1 k $\Omega$
Output Characteristics	Positive polarity unipolar 0-10V, drive current $\pm 100$ mA
BUSY OUT	TTL Output
Preamplifier power supply	D-Sub 9, $\pm$ 12V, $\pm$ 24V (compliant with NIM standards)
Power consumption	+12V (160mA) +24V (40mA), -24V (40mA)
Dimensions weight	NIM1 width 34(W) x 221(H) x 249(D) mm, Approximately 975g
	Tak Git



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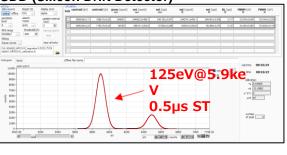


Rear

#### HPGe semiconductor detector



#### SDD (Silicon Drift Detector)



\*Images is for illustration purpose. \*Please note that contents may change without prior notice.

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